

Lonten N-channel 45V, 43A, 14m Ω Power MOSFET

| Description | Product Summary | |
|-----------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------------|
| These N-Channel enhancement mode power field | V _{DSS} 45V | |
| effect transistors are using trench DMOS | $R_{DS(on).max}$ @ V_{GS} =10V 14m Ω | |
| technology. This advanced technology has been | I _D 43A | |
| especially tailored to minimize on-state resistance, | | |
| provide superior switching performance, and with | | |
| stand high energy pulse in the avalanche and | | |
| commutation mode. These devices are well suited | Pin Configuration | |
| for high efficiency fast switching applications. | | |
| | | |
| Features | | |
| • $45V,43A,R_{DS(ON),max}=14m\Omega@V_{GS}=10V$ | Solution in the second | |
| Improved dv/dt capability | | ΪD |
| Fast switching 100% EAS Guaranteed | a | |
| | TO 254 TO 252 | _ i+┐ ∔ |
| Green device available | TO-251 TO-252 | ▫⊢⊢ |
| Applications | | • _S |
| Motor Drives | | |
| ↓ UPS | N-Channel MOSFET | \sim |
| DC-DC Converter | | Pb |
| | | |

Absolute Maximum Ratings T_c = 25°C unless otherwise noted

| Parameter | Symbol | Value | Unit | |
|---------------------------------------------------|------------------|-------------|------|--|
| Drain-Source Voltage | V _{DSS} | 45 | V | |
| Continuous drain current ($T_c = 25^{\circ}C$) | | 43 | А | |
| Continuous drain current ($T_c = 100^{\circ}C$) | I _D | 28 | А | |
| Pulsed drain current ¹⁾ | I _{DM} | 172 | A | |
| Gate-Source voltage | V _{GSS} | ±20 | V | |
| Avalanche energy ²⁾ | E _{AS} | 49 | mJ | |
| Power Dissipation ($T_c = 25^{\circ}C$) | PD | 54 | W | |
| Storage Temperature Range | T _{STG} | -55 to +150 | °C | |
| Operating Junction Temperature Range | TJ | -55 to +150 | °C | |

Thermal Characteristics

| Parameter | Symbol | Value | Unit |
|--------------------------------------|-----------------------|-------|------|
| Thermal Resistance, Junction-to-Case | $R_{	extsf{	heta}JC}$ | 2.3 | °C/W |



Package Marking and Ordering Information

| Device | Device Package | Marking |
|------------|----------------|------------|
| LNH045R140 | TO-251 | LNH045R140 |
| LNG045R140 | TO-252 | LNG045R140 |

Electrical Characteristics T_J = 25°C unless otherwise noted

| Parameter | Symbol | Test Condition | Min. | Тур. | Max. | Unit |
|-------------------------------------|------------------------|--------------------------------------------------------------------|------|-------|------|------|
| Static characteristics | | | | | | |
| Drain-source breakdown voltage | BV _{DSS} | V _{GS} =0 V, I _D =250uA | 45 | | | V |
| Gate threshold voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250uA | 1.0 | | 2.0 | V |
| 5 | | V_{DS} =45 V, V_{GS} =0 V, T_{J} = 25°C | | | 1 | μA |
| Drain-source leakage current | I _{DSS} | V_{DS} =36 V, V_{GS} =0 V, T_{J} = 125°C | | | 10 | μA |
| Gate leakage current, Forward | I _{GSSF} | V _{GS} =20 V, V _{DS} =0 V | | | 100 | nA |
| Gate leakage current, Reverse | I _{GSSR} | V _{GS} =-20 V, V _{DS} =0 V | | | -100 | nA |
| Decision and the social second | | V _{GS} =10 V, I _D =20 A | | 10.7 | 14 | mΩ |
| Drain-source on-state resistance | R _{DS(on)} | V _{GS} =4.5 V, I _D =10 A | | 13 | 18 | mΩ |
| Forward transconductance | g _{fs} | V _{DS} =5 V , I _D =20A | | 43 | | S |
| Dynamic characteristics | | | | | | |
| Input capacitance | C _{iss} | | | 1360 | | |
| Output capacitance | C _{oss} | $V_{DS} = 25 V, V_{GS} = 0 V,$ F = 1MHz | | 129 | | pF |
| Reverse transfer capacitance | C _{rss} | | | 102 | | |
| Turn-on delay time | t _{d(on)} | | | 10 | | |
| Rise time | tr | V _{DD} = 25V,V _{GS} =10V, I _D =20 A | | 106 | | - ns |
| Turn-off delay time | t _{d(off)} | $v_{DD} = 23v, v_{GS} = 10v, I_D = 20 \text{ A}$ | | 59.2 | | |
| Fall time | t _f | | | 200.8 | | |
| Gate resistance | R _g | V _{GS} =0V, V _{DS} =0V, F=1MHz | | 3.2 | | Ω |
| Gate charge characteristics | | | | | | |
| Gate to source charge | Q _{gs} | | | 5.8 | | |
| Gate to drain charge | Q _{gd} | $V_{DS}=25 V, I_{D}=10A,$ | | 3.9 | | nC |
| Gate charge total | Qg | - V _{GS} = 10 V | | 31.6 | | |
| Drain-Source diode characteristic | s and Maxi | num Ratings | | | | |
| Continuous Source Current | ls | | | | 43 | А |
| Pulsed Source Current ³⁾ | I _{SM} | | | | 172 | А |
| Diode Forward Voltage | V _{SD} | V_{GS} =0V, I _S =10A, T _J =25 $^{\circ}$ C | | | 1.2 | V |
| Reverse Recovery Time | t _{rr} | | | 18.5 | | ns |
| Reverse Recovery Charge | Qrr | l _s =10A,di/dt=100A/us, T _J =25℃ | | 9.8 | | nC |

Notes:

1: Repetitive Rating: Pulse width limited by maximum junction temperature.

2: V_{DD} =25V, V_{GS} =10V, L=0.5mH, I_{AS} =14A, R_G =25 Ω , Starting T_J =25 $^{\circ}$ C.

3: Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.



LNH045R140/LNG045R140



Figure 1. Typ. Output Characteristics

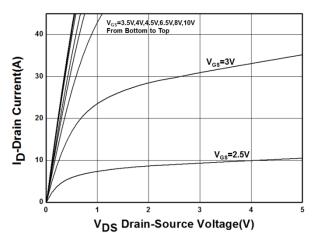
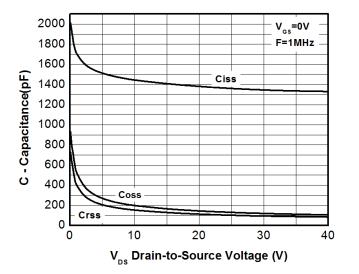
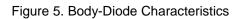
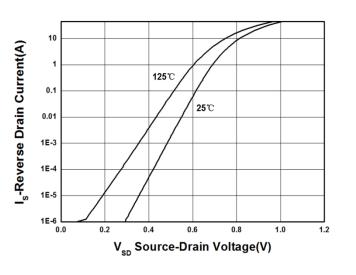
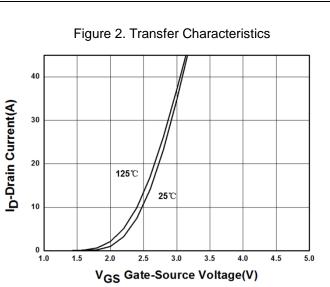


Figure 3. Capacitance Characteristics

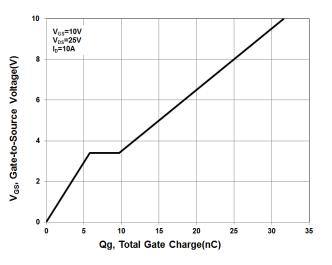


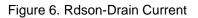


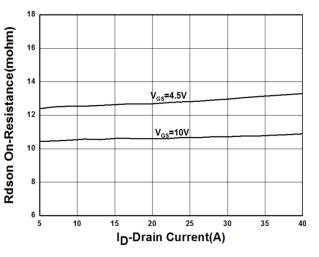














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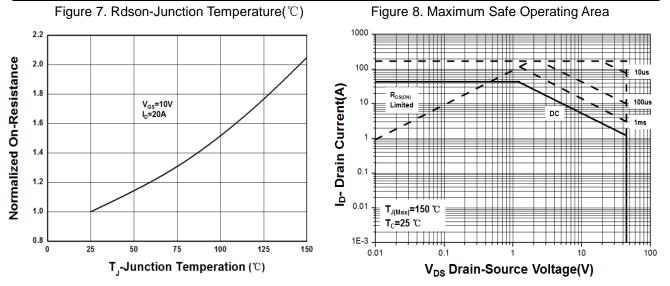
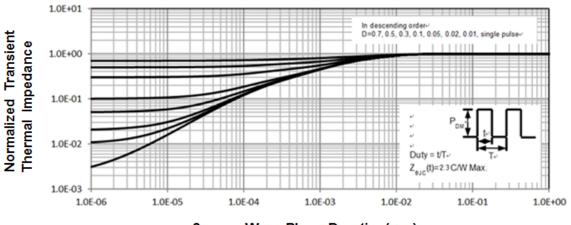


Figure 6. Normalized Maximum Transient Thermal Impedance

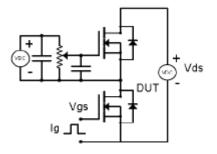


Square Wave Pluse Duration(sec)



Test Circuit & Waveform

Figure 8. Gate Charge Test Circuit & Waveform



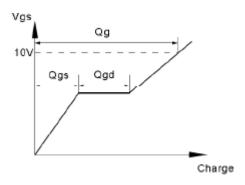


Figure 9. Resistive Switching Test Circuit & Waveforms

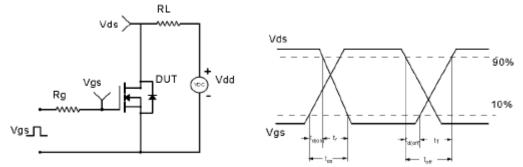
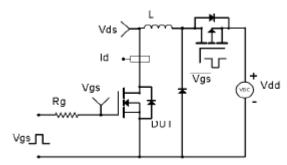
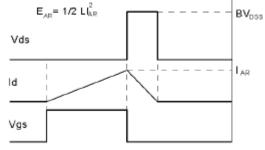
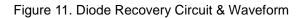
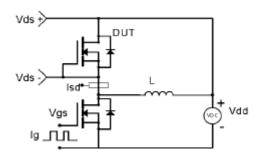


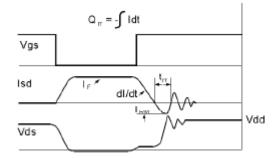
Figure 10. Unclamped Inductive Switching (UIS) Test Circuit & Waveform





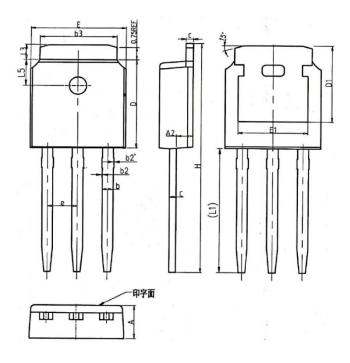






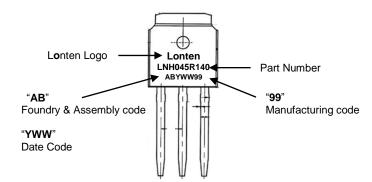


Mechanical Dimensions for TO-251



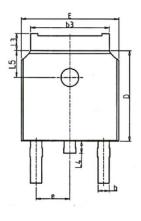
| COMMON DIMENSIONS | | | | | | |
|-------------------|----------|---------|-------|----------|-------|-------|
| SYMBOL MM | | | INCH | | | |
| STIVIDOL | MIN | NOM | MAX | MIN | NOM | MAX |
| А | 2.20 | 2.30 | 2.38 | 0.087 | 0.091 | 0.094 |
| A2 | 0.97 | 1.07 | 1.17 | 0.038 | 0.042 | 0.046 |
| b | 0.68 | 0.78 | 0.90 | 0.027 | 0.031 | 0.035 |
| b2 | 0.00 | 0.04 | 0.10 | 0.000 | 0.002 | 0.004 |
| b2' | 0.00 | 0.04 | 0.10 | 0.000 | 0.002 | 0.004 |
| b3 | 5.20 | 5.33 | 5.46 | 0.205 | 0.210 | 0.215 |
| с | 0.43 | 0.53 | 0.61 | 0.017 | 0.021 | 0.024 |
| D | 5.98 | 6.10 | 6.22 | 0.235 | 0.240 | 0.245 |
| D1 | | 5.30REF | | 0.209REF | | |
| E | 6.40 | 6.60 | 6.73 | 0.252 | 0.260 | 0.265 |
| E1 | 4.63 | - | - | 0.182 | - | - |
| е | 2.286BSC | | | 0.090BSC | | |
| н | 16.22 | 16.52 | 16.82 | 0.639 | 0.650 | 0.662 |
| L1 | 9.15 | 9.40 | 9.65 | 0.360 | 0.370 | 0.380 |
| L3 | 0.88 | 1.02 | 1.28 | 0.035 | 0.040 | 0.050 |
| L5 | 1.65 | 1.80 | 1.95 | 0.065 | 0.071 | 0.077 |

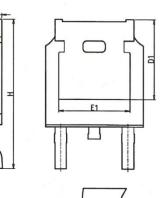
TO-251 Part Marking Information

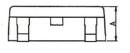


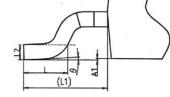


Mechanical Dimensions for TO-252



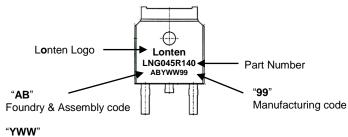






| COMMON DIMENSIONS | | | | | | |
|-------------------|-----------|---------|-------|----------|-------|-------|
| CYMDOL | SYMBOL MM | | INCH | | | |
| STINDUL | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 2.20 | 2.30 | 2.38 | 0.087 | 0.091 | 0.094 |
| A1 | 0.00 | - | 0.20 | 0.000 | - | 0.008 |
| A2 | 0.97 | 1.07 | 1.17 | 0.038 | 0.042 | 0.046 |
| b | 0.68 | 0.78 | 0.90 | 0.027 | 0.031 | 0.035 |
| b3 | 5.20 | 5.33 | 5.46 | 0.205 | 0.210 | 0.215 |
| с | 0.43 | 0.53 | 0.61 | 0.017 | 0.021 | 0.024 |
| D | 5.98 | 6.10 | 6.22 | 0.235 | 0.240 | 0.245 |
| D1 | | 5.30REF | - | 0.209REF | | |
| Е | 6.40 | 6.60 | 6.73 | 0.252 | 0.260 | 0.265 |
| E1 | 4.63 | - | - | 0.182 | - | - |
| е | | 2.286BS | С | 0.090BSC | | |
| Н | 9.40 | 10.10 | 10.50 | 0.370 | 0.398 | 0.413 |
| L | 1.38 | 1.50 | 1.75 | 0.054 | 0.059 | 0.069 |
| L1 | 2.90REF | | | 0.114REF | | |
| L2 | 0.51BSC | | | 0.020BSC | | |
| L3 | 0.88 | - | 1.28 | 0.035 | - | 0.050 |
| L4 | 0.50 | - | 1.00 | 0.020 | - | 0.039 |
| L5 | 1.65 | 1.80 | 1.95 | 0.065 | 0.071 | 0.077 |
| θ | 0° | - | 8° | 0° | - | 8° |

TO-252 Part Marking Information



"YWW" Date Code



LNH045R140/LNG045R140

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